

Low Noise 800mA LDO REGULATOR R1170X series

■ OUTLINE

The R1170 Series are positive voltage regulator ICs by CMOS process. The R1170 Series have features of high ripple rejection, low dropout voltage, high output voltage accuracy, low consumption current. Each of these ICs consists of a voltage reference unit, an error amplifier, resistor net for setting output voltage, a current limit circuit at short mode, a chip enable circuit, and thermal-shunt circuit. Output Voltage of R1170 is fixed in the IC.

Low consumption current by the merit of CMOS process and built-in transistors with low ON-resistance make low dropout voltage and chip enable function prolong the battery life. These regulators are remarkable improvement on the current regulators in terms of ripple rejection, input transient response, and load transient response.

Maximum Output Current is large for its compact size.

Thus, the R1170 Series are suitable for various power sources for portable appliances.

Since the packages for these ICs are the SOT-89-5 package or HSON6 (Under Development), high density mounting of the ICs on boards is possible.

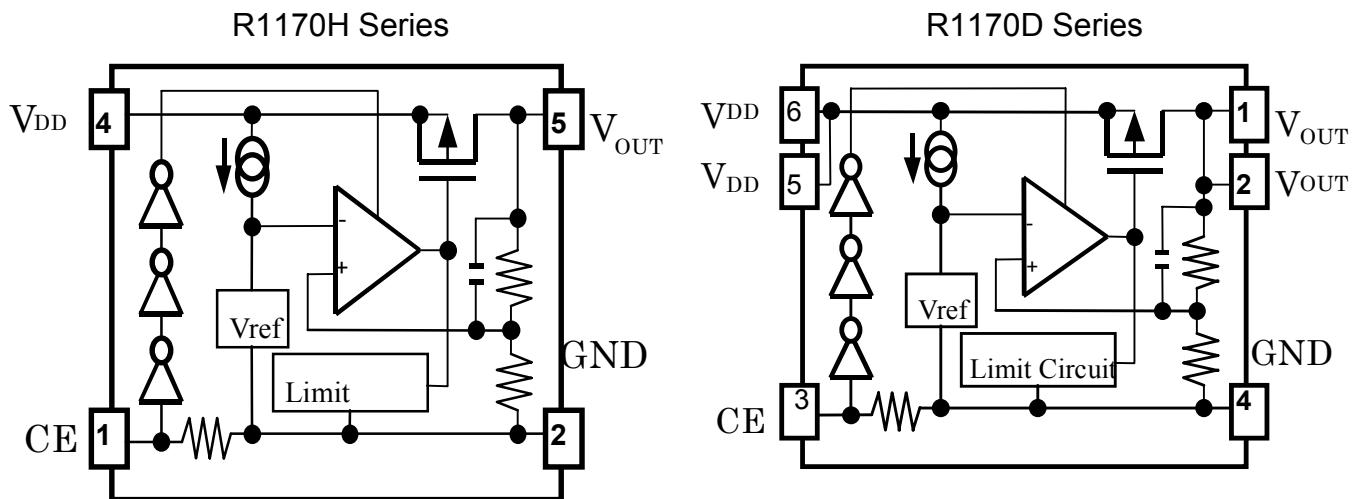
■ FEATURES

- Ultra-Low Supply Current TYP. 80µA
- Low Standby Current TYP. 0.1µA
- Output Current MIN. 800mA(V_{IN}=V_{OUT}+1.0V)
- Output Voltage Stepwise setting with a step of 0.1V in the range of 1.5V to 4.0V
- High Output Voltage Accuracy ±2.0%
- Low Dropout Voltage TYP. 0.12V(V_{OUT}=3.0V, I_{OUT}=300mA)
- Line Regulation TYP. 0.05%/V
- Small Package SOT-89-5, HSON6
- Built-in Current Limit Circuit
- Built-in Thermal Shunt Circuit
- Low Temperature-drift Coefficient of Output Voltage TYP.±100ppm/°C

■ APPLICATIONS

- Local Power source for Notebook PC.
- Local Power source for portable appliances, cameras, and videos.
- Local Power source for equipment of battery-use.
- Local Power source for home appliances.

■ BLOCK DIAGRAMS



■ SELECTION GUIDE

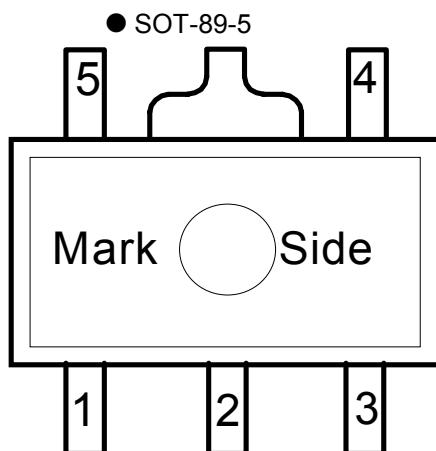
The output voltage, the chip-enable polarity, the taping type can be selected at the user's request. The selection can be made with the part number as follows;

R1170X XXXX-XX ← Part Number

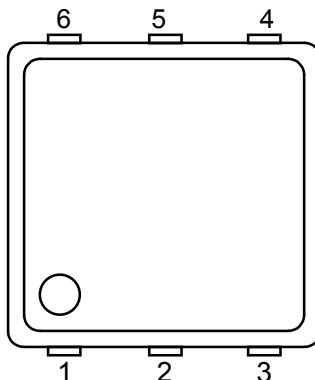
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a b c d

Code	Contents
a	Package Type; H: SOT89-5, D: HSON-6P
b	Designation of Output Voltage(V _{OUT}) Stepwise setting with 0.1V increment in the range from 1.5V to 4.0V
c	Designation of option; A: Built-in Chip Enable Circuit, Active at "L" B: Built-in Chip Enable Circuit, Active at "H"
d	Designation of Taping Type; T1 or T2 (Refer to Taping Specifications)

■ PIN CONFIGURATION



● HSON-6P (Under Development)



■ PIN DESCRIPTION

SOT89-5

Pin No.	Symbol	Description
1	CE or CE	Chip Enable Pin Voltage Regulator Output Pin
2	GND	Ground Pin
3	VDD	Input Pin
4	VOUT	Voltage Regulator Output Pin
5	NC	No Connection

HSON-6P

Pin No.	Symbol	Description
1	VOUT	Voltage Regulator Output Pin
2	VOUT	Voltage Regulator Output Pin
3	CE or CE	Chip Enable Pin Voltage Regulator Output Pin
4	GND	Ground Pin
5	VDD	Input Pin
6	VDD	Input Pin

■ ABSOLUTE MAXIMUM RATINGS

Item	Symbol	Rating	Unit
Input Voltage	VIN	7.0	V
Input Voltage(CE or CE Input Pin)*Note	VCE	-0.3 ~ VIN+0.3	V
Output Voltage	VOUT	-0.3 ~ VIN+0.3	V
Output Current	IOUT	1.2	A
Power Dissipation	PD	Internally limited	
Operating Temperature	T _{opt}	-40 ~ 85	°C
Storage Temperature	T _{stg}	-55 ~ 125	°C

■ ELECTRICAL CHARACTERISTICS

● R1170XxxA

(Topt=25°C)

Item	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input Voltage	VIN				6.0	V
Supply Current1	ISS1	VIN-VOUT=1.0V VCE=GND		80	160	µA
Standby Current	Istb	VIN=VCE=6.0V		0.1	1.0	µA
Output voltage	VOUT	VIN-VOUT=1.0V IOUT=100mA	x0.98		x1.02	V
Output Current	IOUT1	VIN-VOUT=1.0V	800			mA
Load regulation	ΔVOUT/ ΔIOUT	VIN-VOUT=1.0V 1mA≤IOUT≤300mA		30	100	mV
Dropout Voltage	VDIF	IOUT=300mA	Refer to Dropout Voltage Table			
Line regulation	ΔVOUT/ ΔVIN	IOUT=100mA VOUT+0.5V≤VIN≤8.0V		0.05	0.30	%/V
Ripple Rejection	RR	f=1kHz, Ripple 0.5Vp-p VIN-VOUT=1.0V		50		dB
Output Voltage Temperature Coefficient	ΔVOUT/ ΔT	IOUT=10mA -40°C ≤ Topt ≤ 85°C		±100		ppm /°C
Short Current Limit	ILIM	VOUT=0V		40		mA
Pull-up resistance for CE pin	RPU		1.25	2.50	5.00	MΩ
CE Input Voltage "H"	VCEH		1.50		VIN	V
CE Input Voltage "L"	VCEL		0.00		0.25	V
Thermal Shutdown Detector Threshold Temperature	TTSD	Junction Temperature		150		°C
Thermal Shutdown Released Temperature	TTSR	Junction Temperature		120		°C

●R1170xxxxB

(Topt=25°C)

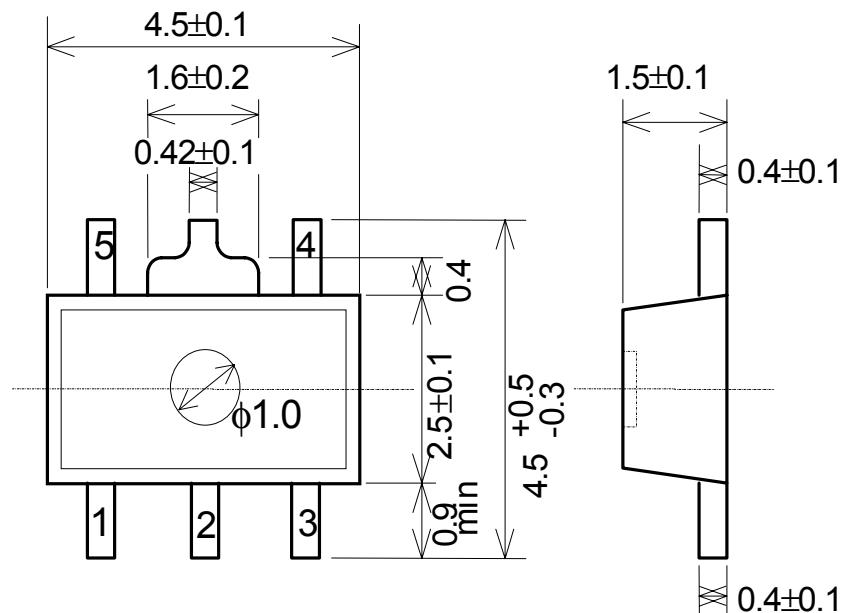
Item	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Input voltage	VIN				6.0	V
Supply Current1	ISS1	VIN-VOUT=1.0V VCE=VIN		80	160	µA
Standby Current	Istb	VIN=6.0V, VCE=GND		0.1	1.0	µA
Reference Voltage for Adjustable Voltage Regulator	VOUT	VIN-VOUT=1.0V IOUT=100mA	x0.98		x1.02	V
Output Current	IOUT1	VIN-VOUT=1.0V	800			mA
Load regulation	ΔVOUT/ ΔIOUT	VIN-VOUT=1.0V 1mA≤IOUT≤300mA		30	100	mV
Dropout Voltage	VDF	IOUT=300mA		Refer to Dropout Voltage Table		
Line regulation	ΔVOUT/ ΔVIN	IOUT=100mA VOUT+0.5V≤VIN≤8.0V		0.05	0.30	%/V
Ripple Rejection	RR	f=1kHz, Ripple 0.5Vp-p		50		dB
Output Voltage Temperature Coefficient	ΔVOUT/ ΔT	-40°C≤Topt≤85°C		±100		ppm /°C
Short Current Limit	ILIM	VOUT=0V		40		mA
Pull-down resistance for CE pin	RPD		1.25	2.5	5	MΩ
CE Input Voltage "H"	VCEH		1.5		VIN	V
CE Input Voltage "L"	VCEL		0		0.25	V
Thermal Shutdown Detector Threshold Temperature	TTSD	Junction Temperature		150		°C
Thermal Shutdown Released Temperature	TTSR	Junction Temperature		120		°C

●Dropout Voltage by Output Voltage (Topt=25°C)

Output Voltage VOUT(V)	Dropout Voltage (V)	
	TYP.	MAX.
VOUT=1.5	0.35	0.45
VOUT=1.6	0.30	0.35
VOUT=1.7	0.25	0.30
1.8≤VOUT≤2.0	0.20	0.25
2.1≤VOUT≤2.4	0.15	0.20
2.5≤VOUT≤4.0	0.12	0.18

■ PACKAGE DIMENSIONS

SOT-89-5



HSON6(Under Development)